

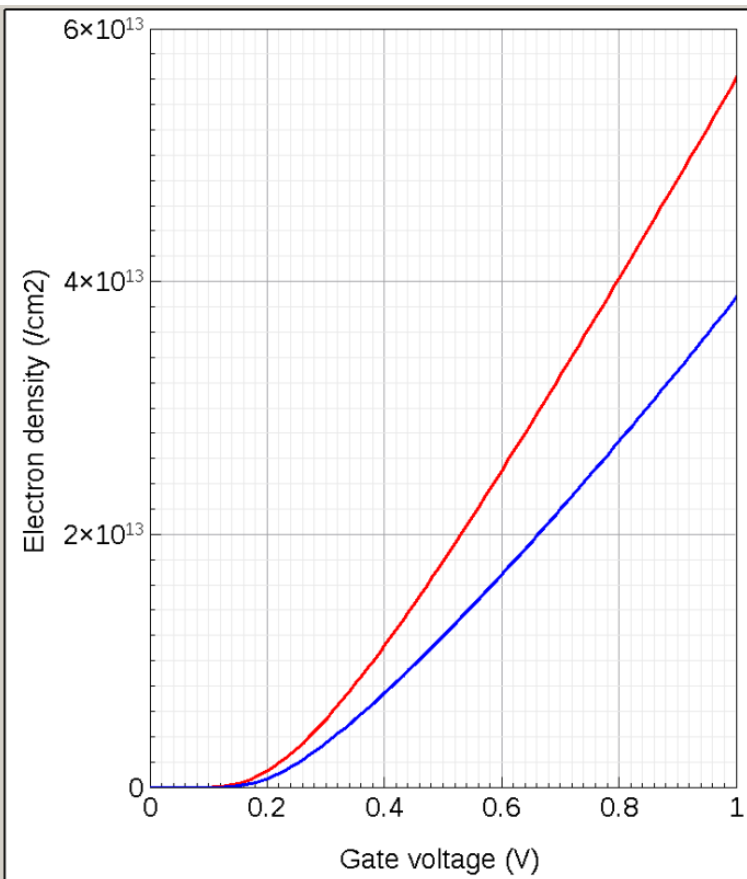
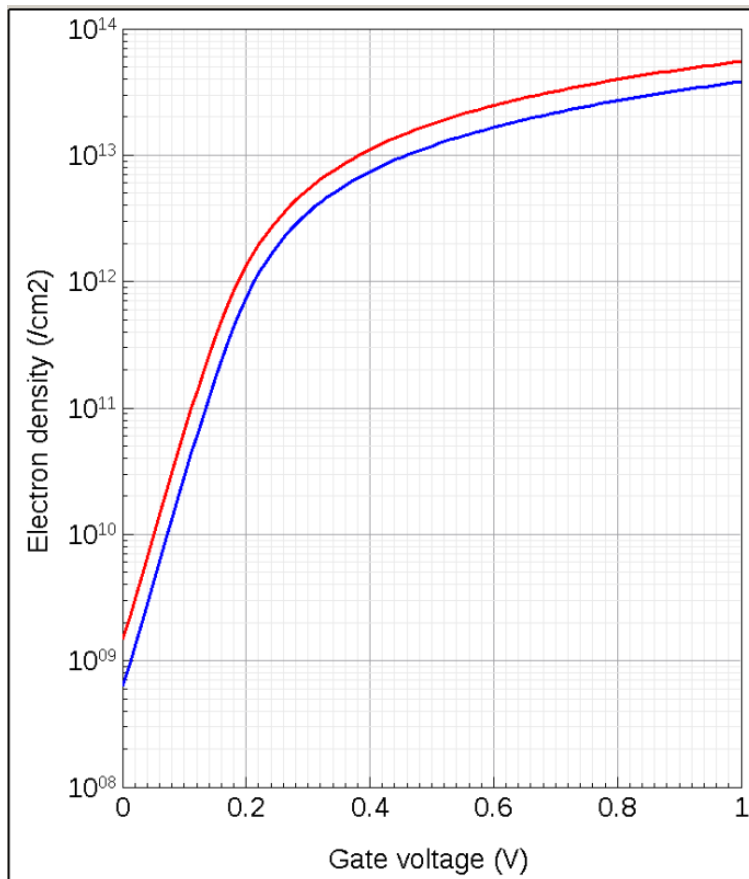
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# Lecture11

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# Answer of Homework#6





# Notice

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- No lecture on October 29
  - Currently, no make-up session will be provided.
- No lecture on December 3 and 5
  - One make-up session on October 31
  - We need one more!

# How to find $n(x, y, z)$

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- The total number is known. But, how can we find  $n(x, y, z)$ ?
  - Each state,  $\psi_{k_x, k_y, n}(x, y, z)$ , contributes  $|\psi_{k_x, k_y, n}(x, y, z)|^2$ .
  - Recall that the wavefunction can be written as
$$\psi_{k_x, k_y, n}(x, y, z) = A_{k_x, k_y, n} e^{+ik_x x} e^{+ik_y y} \psi_{z, n}(z)$$
  - Then,  $|\psi_{k_x, k_y, n}(x, y, z)|^2 = |A_{k_x, k_y, n}|^2 |\psi_{z, n}(z)|^2$
  - Integration of  $|\psi_{k_x, k_y, n}(x, y, z)|^2$  over the box should give unity.

$$L_x L_y |A_{k_x, k_y, n}|^2 \int_0^{L_z} dz |\psi_{z, n}(z)|^2 = 1$$



# Normalization of $\psi_{z,n}(z)$

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- If  $\psi_{z,n}(z)$  is normalized in the 1D structure,
  - We have the following condition:

$$\left| A_{k_x, k_y, n} \right|^2 = \frac{1}{L_x L_y}$$

- Therefore, each state contributes

$$\left| \psi_{k_x, k_y, n}(x, y, z) \right|^2 = \frac{1}{L_x L_y} \left| \psi_{z,n}(z) \right|^2$$

- Note that every state in a subband has the same electron density.  
(In general, it does not hold.)



# 1D infinite potential well

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- When  $\psi_{z,n}(z) = A_{z,n} \sin\left(\frac{n\pi}{L_z} z\right)$ ,
  - The value of  $A_{z,n}$  is  $\sqrt{\frac{2}{L_z}}$ .
  - Therefore, when fully occupied, a state in the  $n$ -th subband contributes an electron density of (per spin)
$$\frac{2}{L_x L_y L_z} \sin^2\left(\frac{n\pi}{L_z} z\right)$$
  - Finally, the electron density can be obtained by considering all subbands.



# MATLAB example (1)

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- Preparing some constants (the same as before)

```
h = 6.626176e-34; % Planck constant, J s
hbar = h / (2*pi); % Reduced Planck constant, J s
q = 1.602192e-19; % Elementary charge, C
m0 = 9.109534e-31; % Electron rest mass, kg
k_B = 1.380662e-23; % Boltzmann constant, J/K
T = 300.0; % Temperature, K
Lx = 100e-9; Ly = 100e-9; Lz = 5e-9; % Lengths, m
mxx = 0.19; myy = 0.19; mzz = 0.91; % Masses, m0
nmax = 10;
coef = 2*Lx*Ly/(2*pi)*sqrt(mxx*myy)*m0/(hbar^2)*(k_B*T);
```

# MATLAB example (2)

- Calculation of elec

```
totalNumber = 0;
```

```
Nz = 51;
```

```
z = transpose([0:Nz-1])*Lz/(Nz-1);
```

```
elec = zeros(Nz,1); % Electron density, /m^3
```

```
for n=1:nmax
```

```
    Ez = (hbar^2)/(2*mzz*m0)*(pi*n/Lz)^2;
```

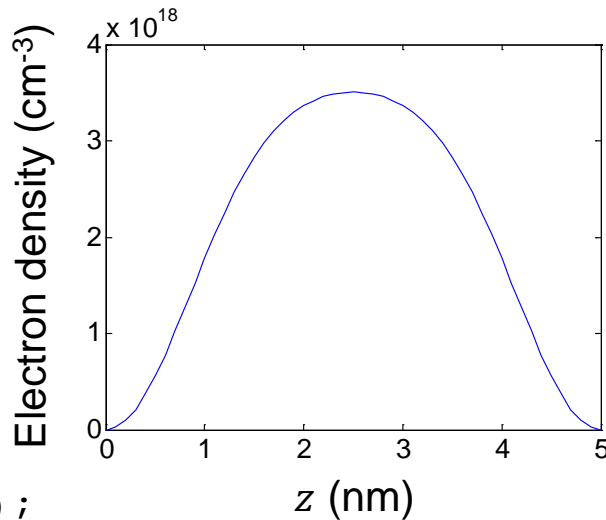
```
    subbandNumber = coef*log(1+exp(-Ez/(k_B*T)));
```

```
    totalNumber = totalNumber + subbandNumber;
```

```
    elec = elec + 2/(Lx*Ly*Lz)*(sin(n*pi*z/Lz).^2)*subbandNumber;
```

```
end
```

```
plot(z/1e-9,elec/1e6)
```







# Homework#7

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- Due: AM08:00, October 22
- Problem#1
  - Up to now, we have assumed that the Fermi energy is 0 eV.
  - In this problem, a 5-nm-thick potential well is considered again.
  - You can set it to any value. (-0.1 eV to +0.1 eV)
  - Calculate the integrated electron density (/cm<sup>2</sup>) as a function of the Fermi energy.
  - Show snapshots of the electron density for different Fermi energies.